

SN65C116xE 具有 $\pm 15\text{kV}$ ESD 保护的双路差分驱动器和接收器

1 特性

- 达到或超出 TIA/EIA-422-B 和 ITU Recommendation V.11 标准的要求
- 使用 5V 单电源供电
- 为 RS-422 总线引脚提供 ESD 保护
 - $\pm 15\text{kV}$ 人体放电模型 (HBM)
 - $\pm 8\text{kV}$ IEC 61000-4-2, 接触放电
 - $\pm 8\text{kV}$ IEC 61000-4-2, 空气间隙放电
- 低电源电流要求: 9mA (最大值)
- 低脉冲偏斜
- 接收器输入阻抗: $17\text{k}\Omega$ (典型值)
- 接收器输入灵敏度: $\pm 200\text{mV}$
- 接收器共模输入电压范围为 -7V 至 +7V
- 无干扰上电和断电保护
- 接收器三态输出低电平有效使能 (仅限 SN65C1167E)

2 应用

- 交流和伺服电机驱动器
- 工厂自动化和控制
- 无线基础设施

3 说明

SN65C1167E 和 SN65C1168E 由双驱动器和双接收器组成, 具有 $\pm 15\text{kV}$ ESD (人体放电模型 [HBM]) 和 $\pm 8\text{kV}$ ESD (IEC61000-4-2 空气间隙放电和接触放电) 保护, 适用于 RS-422 总线引脚。这些器件符合 TIA/EIA-422-B 和 ITU 建议 V.11 的要求。

SN65C1167E 整合了双三态差分线路驱动器和三态差分线路接收器, 两者均采用 5V 单电源供电。驱动器和接收器分别具有高电平有效和低电平有效使能端, 它们可以在外部连接在一起, 用作方向控制。

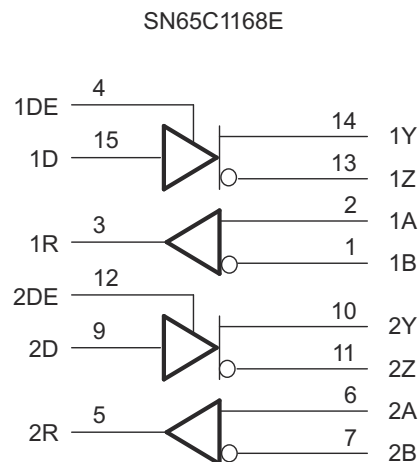
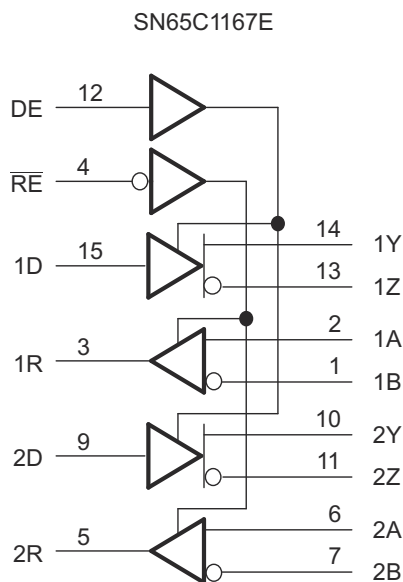
SN65C1168E 驱动器具有单独的高电平有效使能端。

封装信息

器件型号	封装 ⁽¹⁾	封装尺寸 ⁽²⁾
SN65C116xE	SO (16)	10.3mm × 5.3mm
	TSSOP (16)	5mm × 4.4mm
	VQFN (16)	4mm × 3.5mm

(1) 有关更多信息, 请参阅节 11。

(2) 封装尺寸 (长 × 宽) 为标称值, 并包括引脚 (如适用)。



Copyright © 2017, Texas Instruments Incorporated

方框图



Table of Contents

1 特性	1	7.3 Feature Description.....	11
2 应用	1	7.4 Device Functional Modes.....	12
3 说明	1	8 Application and Implementation	13
4 Pin Configuration and Functions	3	8.1 Application Information.....	13
5 Specifications	5	8.2 Typical Application.....	14
5.1 Absolute Maximum Ratings.....	5	8.3 Power Supply Recommendations.....	14
5.2 Driver Output and Receiver Input ESD Ratings.....	5	9 Device and Documentation Support	15
5.3 Recommended Operating Conditions.....	6	9.1 Device Support.....	15
5.4 Thermal Information.....	6	9.2 Receiving Notification of Documentation Updates....	15
5.5 Driver Section Electrical Characteristics.....	7	9.3 支持资源.....	15
5.6 Receiver Section Electrical Characteristics.....	7	9.4 Trademarks.....	15
5.7 Driver Section Switching Characteristics.....	8	9.5 静电放电警告.....	15
5.8 Receiver Section Switching Characteristics.....	8	9.6 术语表.....	15
6 Parameter Measurement Information	9	10 Revision History	15
7 Detailed Description	11	11 Mechanical, Packaging, and Orderable Information	15
7.1 Overview.....	11		
7.2 Functional Block Diagram.....	11		

4 Pin Configuration and Functions

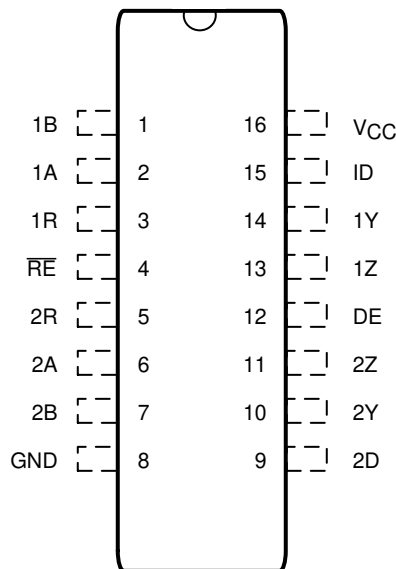


图 4-1. NS or PW Package 16 Pin (NS or TSSOP)
Top View

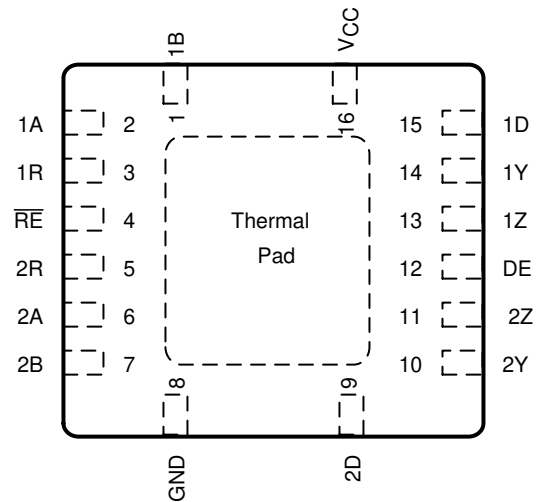


图 4-2. RGY Package 16 Pin (VQFN) Top View

表 4-1. Pin Functions, SN65C1167E

NAME	PIN			I/O	DESCRIPTION
	SO	TSSOP	VQFN		
1A	2	2	2	I	RS422 differential input (noninverting) to receiver 1
2A	6	6	6	I	RS422 differential input (noninverting) to receiver 2
1B	1	1	1	I	RS422 differential input (inverting) to receiver 1
2B	7	7	7	I	RS422 differential input (inverting) to receiver 2
1D	15	15	15	I	Logic data input to RS422 driver 1
2D	9	9	9	I	Logic data input to RS422 driver 2
DE	12	12	12	I	Driver enable (active high)
GND	8	8	8	—	Device ground pin
1R	3	3	3	O	Logic data output of RS422 receiver 1
2R	5	5	5	O	Logic data output of RS422 receiver 2
RE	4	4	4	I	Receiver enable pin (active low)
V _{CC}	16	16	16	—	Power supply
1Y	14	14	14	O	RS-422 differential (noninverting) driver output 1
2Y	10	10	10	O	RS-422 differential (noninverting) driver output 2
1Z	13	13	13	O	RS-422 differential (inverting) driver output 1
2Z	11	11	11	O	RS-422 differential (inverting) driver output 2

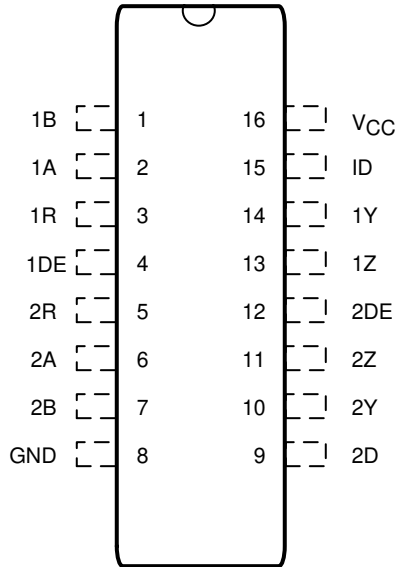


图 4-3. NS or PW Package 16 Pin (NS or TSSOP) Top View

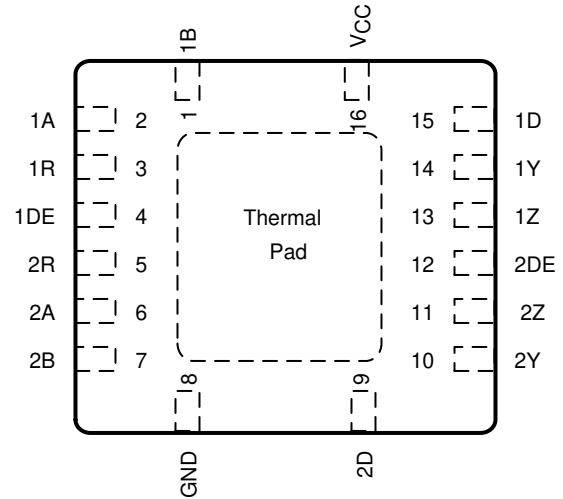


图 4-4. RGY Package 16 Pin (VQFN) Top View

表 4-2. Pin Functions, SN65C1168E

NAME	PIN			I/O	DESCRIPTION
	SO	TSSOP	VQFN		
1A	2	2	2	I	RS422 differential input (noninverting) to receiver 1
2A	6	6	6	I	RS422 differential input (noninverting) to receiver 2
1B	1	1	1	I	RS422 differential input (inverting) to receiver 1
2B	7	7	7	I	RS422 differential input (inverting) to receiver 2
1D	15	15	15	I	Logic data input to RS422 driver 1
2D	9	9	9	I	Logic data input to RS422 driver 2
1DE	4	4	4	I	Driver 1 enable (active high)
2DE	12	12	12	I	Driver 2 enable (active high)
GND	8	8	8	—	Device ground
1R	3	3	3	O	Logic data output of RS422 receiver 1
2R	5	5	5	O	Logic data output of RS422 receiver 2
V _{CC}	16	16	16	—	Power supply
1Y	14	14	14	O	RS-422 differential (noninverting) driver output 1
2Y	10	10	10	O	RS-422 differential (noninverting) driver output 2
1Z	13	13	13	O	RS-422 differential (noninverting) driver output 1
2Z	11	11	11	O	RS-422 differential (noninverting) driver output 2

5 Specifications

5.1 Absolute Maximum Ratings

over recommended operating free-air temperature range (unless otherwise noted) ⁽¹⁾

		MIN	MAX	UNIT
V _{CC}	Supply voltage ⁽²⁾	- 0.5	7	V
V _I	Input voltage	Driver, DE, RE	- 0.5	7
		A or B, Receiver	- 14	14
V _{ID}	Differential input voltage ⁽³⁾	Receiver	- 14	14
V _O	Output voltage	Driver	- 0.5	7
		Receiver	- 0.5	V _{CC} + 0.5
I _{IK}	Input clamp current	Driver, V _I < 0		- 20
I _{OK}	Output clamp current	Driver, V _O < 0		- 20
		Receiver		±20
I _O	Output current	Driver		±150
		Receiver		±25
I _{CC}	Supply current			200
		GND current		- 200
T _J	Operating virtual junction temperature			150
T _A	Operating free-air temperature	- 40	85	°C
T _{stg}	Storage temperature	- 65	150	°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values except differential input voltage are with respect to the network GND.
- (3) Differential input voltage is measured at the noninverting terminal, with respect to the inverting terminal.

5.2 Driver Output and Receiver Input ESD Ratings

		VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±15000
		Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1000
		IEC 61000-4-2, air-gap discharge	±8000
		IEC 61000-4-2, contact discharge	±8000

- (1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage	4.5	5	5.5	V
V _{IC}	Common-mode input voltage ⁽¹⁾			±7	V
V _{ID}	Differential input voltage			±7	V
V _I	Input voltage	0		5.5	V
V _O	Output voltage	0		V _{CC}	V
V _{IH}	High-level input voltage	2			V
V _{IL}	Low-level input voltage			0.8	V
I _{OH}	High-level output current	Receiver		-6	mA
		Driver		-20	
I _{OL}	Low-level output current	Receiver		6	mA
		Driver		20	
T _A	Operating free-air temperature	-40		85	°C

(1) Refer to TIA/EIA-422-B for exact conditions.

5.4 Thermal Information

THERMAL METRIC ⁽¹⁾	SN65C116xE			UNIT	
	SO (NS)	PW (TSSOP)	RGY (VQFN)		
	16 PINS	16 PINS	16 PINS		
R _{θJA}	Junction-to-ambient thermal resistance	88.5	107.5	48.4	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	46.2	38.4	46.4	°C/W
R _{θJB}	Junction-to-board thermal resistance	50.7	53.7	24.6	°C/W
ψ _{JT}	Junction-to-top characterization parameter	13.5	3.2	2.3	°C/W
ψ _{JB}	Junction-to-board characterization parameter	50.3	53.1	24.5	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	n/a	n/a	8.5	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

5.5 Driver Section Electrical Characteristics

over recommended supply voltage and operating free-air temperature ranges (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP ⁽¹⁾	MAX	UNIT
V _{IK}	Input clamp voltage	I _I = -18mA				-1.5	V
V _{OH}	High-level output voltage	V _{IH} = 2V,	V _{IL} = 0.8V, I _{OH} = -20mA	2.4	3.5		V
V _{OL}	Low-level output voltage	V _{IH} = 2V,	V _{IL} = 0.8V, I _{OL} = 20mA		0.2	0.4	V
V _{OD1}	Differential output voltage 1	I _O = 0mA		2		6	V
V _{OD2}	Differential output voltage 2	R _L = 100Ω,	See 图 6-1 (2)	2	3.7		V
Δ V _{OD}	Change in magnitude of differential output voltage	R _L = 100Ω,	See 图 6-1 (2)			±0.4	V
V _{OC}	Common-mode output voltage	R _L = 100Ω,	See 图 6-1 (2)			±3	V
Δ V _{OC}	Change in magnitude of common-mode output voltage	R _L = 100Ω,	See 图 6-1 (2)			±0.4	V
I _{O(OFF)}	Output current with power off	V _{CC} = 0V	V _O = 6V V _O = -0.25V			100 100	μA
I _{OZ}	High-impedance-state output current	V _O = 2.5V V _O = 5V				20 -20	μA
I _{IH}	High-level input current	V _I = V _{CC} or V _{IH}				1	μA
I _{IL}	Low-level input current	V _I = GND or V _{IL}				-1	μA
I _{OS}	Short-circuit output current	V _O = V _{CC} or GND ⁽³⁾		-30		-150	mA
I _{CC}	Supply current (total package)	No load, Enabled	V _I = V _{CC} or GND V _I = 2.4 or 0.5V ⁽⁴⁾		4 5	6 9	mA
C _i	Input capacitance				6		pF

(1) All typical values are at V_{CC} = 5V and T_A = 25°C.

(2) Refer to TIA/EIA-422-B for exact conditions.

(3) Not more than one output should be shorted at a time, and the duration of the short circuit should not exceed one second.

(4) This parameter is measured per input, while the other inputs are at V_{CC} or GND.

5.6 Receiver Section Electrical Characteristics

over recommended ranges of common-mode input voltage, supply voltage, and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP ⁽¹⁾	MAX	UNIT
V _{IT+}	Positive-going input threshold voltage, differential input					0.2	V
V _{IT-}	Negative-going input threshold voltage, differential input			-0.2 ⁽²⁾			V
V _{hys}	Input hysteresis (V _{IT+} - V _{IT-})				60		mV
V _{IK}	Input clamp voltage, RE	SN65C1167E	I _I = -18mA			-1.5	V
V _{OH}	High-level output voltage	V _{ID} = 200mV, I _{OH} = -6mA		3.8	4.2		V
V _{OL}	Low-level output voltage	V _{ID} = -200mV, I _{OL} = 6mA			0.1	0.3	V
I _{OZ}	High-impedance state output current	SN65C1167E	V _O = V _{CC} or GND		±0.5	±5	μA
I _I	Line input current	Other input at 0V				1.5 -2.5	mA
I _I	Enable input current, RE	SN65C1167E	V _I = V _{CC} or GND			±1	μA
r _i	Input resistance	V _{IC} = -7V to 7V, Other input at 0V		4	17		kΩ
I _{CC}	Supply current (total package)	No load, Enabled	V _I = V _{CC} or GND V _{IH} = 2.4V or 0.5V ⁽³⁾		4 5	6 9	mA

(1) All typical values are at V_{CC} = 5V and T_A = 25°C.

(2) The algebraic convention, where the less positive (more negative) limit is designated as minimum, is used in this data sheet for common-mode input voltage and threshold voltage levels only.

(3) Refer to TIA/EIA-422-B for exact conditions.

5.7 Driver Section Switching Characteristics

over recommended supply voltage and operating free-air temperature ranges (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP ⁽¹⁾	MAX	UNIT
t_{PHL}	Propagation delay time, high- to low-level output	R1 = R2 = 50 Ω , C1 = C2 = C3 = 40pF, See 图 6-2	R3 = 500 Ω , S1 is open,		8	16	ns
t_{PLH}	Propagation delay time, low- to high-level output				8	16	ns
$t_{sk(p)}$	Pulse skew				1.5	4	ns
t_r	Rise time	R1 = R2 = 50 Ω , C1 = C2 = C3 = 40pF, See 图 6-3	R3 = 500 Ω , S1 is open,		5	8	ns
t_f	Fall time				5	8	ns
t_{PZH}	Output-enable time to high level	R1 = R2 = 50 Ω , C1 = C2 = C3 = 40pF, See 图 6-4	R3 = 500 Ω , S1 is closed,		10	19	ns
t_{PZL}	Output-enable time to low level				10	19	ns
t_{PHZ}	Output-disable time from high level	R1 = R2 = 50 Ω , C1 = C2 = C3 = 40pF, See 图 6-4	R3 = 500 Ω , S1 is closed,		7	16	ns
t_{PLZ}	Output-disable time from low level				7	16	ns
f_{SW}	Maximum switching frequency	R1 = R2 = 50 Ω , C1 = C2 = C3 = 40pF, See 图 6-3	R3 = 500 Ω , S1 is open,	20			MHz

(1) All typical values are at $V_{CC} = 5V$ and $T_A = 25^\circ C$.

5.8 Receiver Section Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted)⁽²⁾

PARAMETER		TEST CONDITIONS		MIN	TYP ⁽¹⁾	MAX	UNIT
t_{PLH}	Propagation delay time, low- to high-level output	See 图 6-5		9	15	27	ns
t_{PHL}	Propagation delay time, high- to low-level output	See 图 6-5		9	15	27	ns
t_{TLH}	Transition time, low- to high-level output	$V_{IC} = V$, See 图 6-5			4	9	ns
t_{THL}	Transition time, high- to low-level output				4	9	ns
t_{PZH}	Output-enable time to high level	SN65C1167E	$R_L = 1k\Omega$, $C_L = 50pF$ See 图 6-6		7	22	ns
t_{PZL}	Output-enable time to low level				7	22	ns
t_{PHZ}	Output-disable time from high level				12	22	ns
t_{PLZ}	Output-disable time from low level				12	22	ns

(1) All typical values are at $V_{CC} = 5V$ and $T_A = 25^\circ C$.

(2) Measured per input while the other inputs are at V_{CC} or GND

6 Parameter Measurement Information

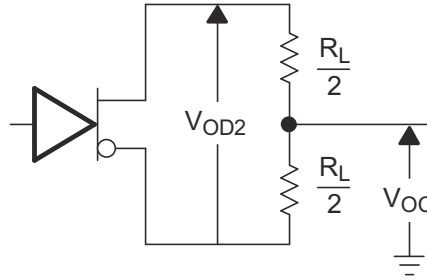
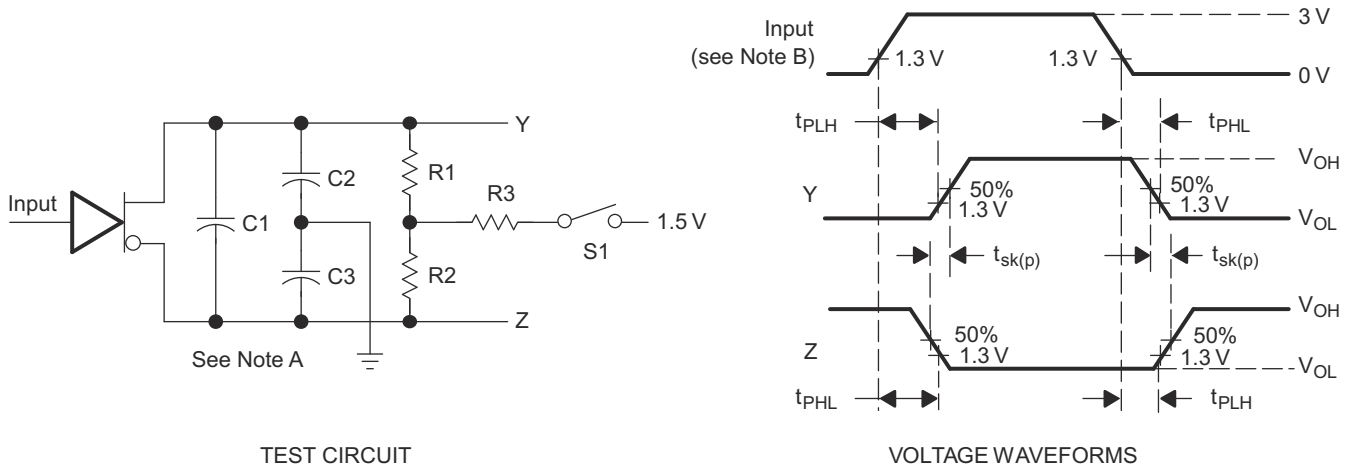
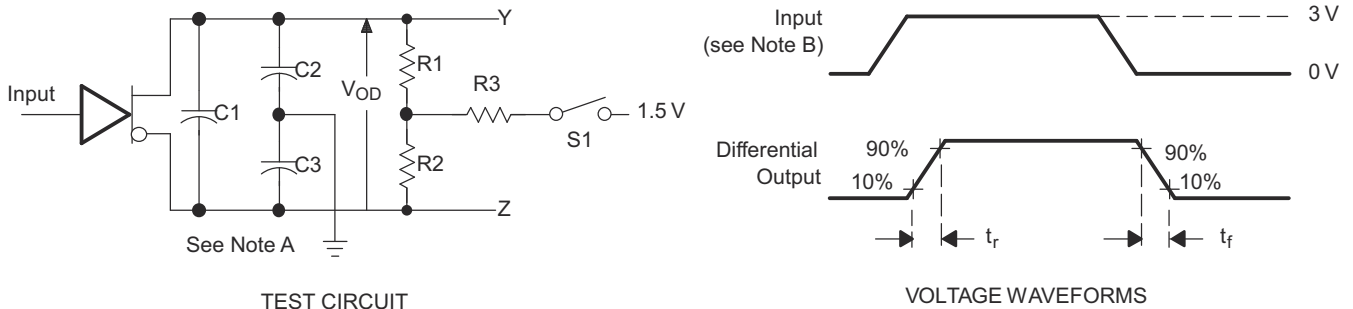


图 6-1. Driver Test Circuit, V_{OD2} and V_{OC}



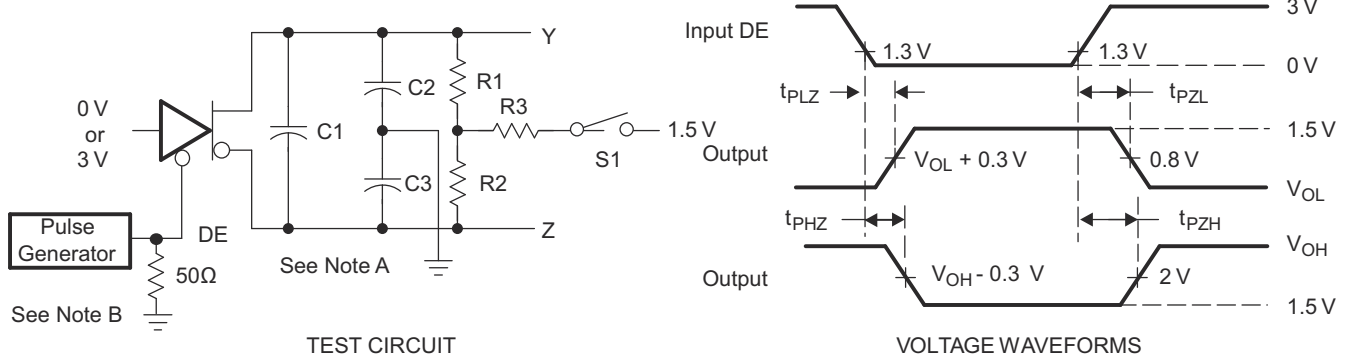
- A. C1, C2, and C3 include probe and jig capacitance.
B. The input pulse is supplied by a generator having the following characteristics: PRR = 1 MHz, duty cycle = 50%, $t_r = t_f \leq 6$ ns.

图 6-2. Driver Test Circuit and Voltage Waveforms



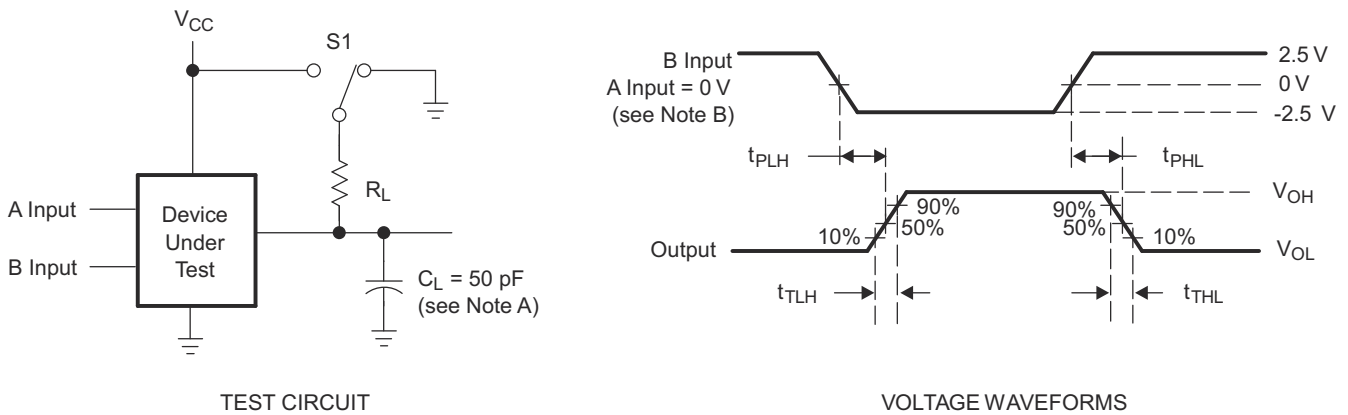
- A. C1, C2, and C3 include probe and jig capacitance.
B. The input pulse is supplied by a generator having the following characteristics: PRR = 1 MHz, duty cycle = 50%, $t_r = t_f \leq 6$ ns.

图 6-3. Driver Test Circuit and Voltage Waveforms



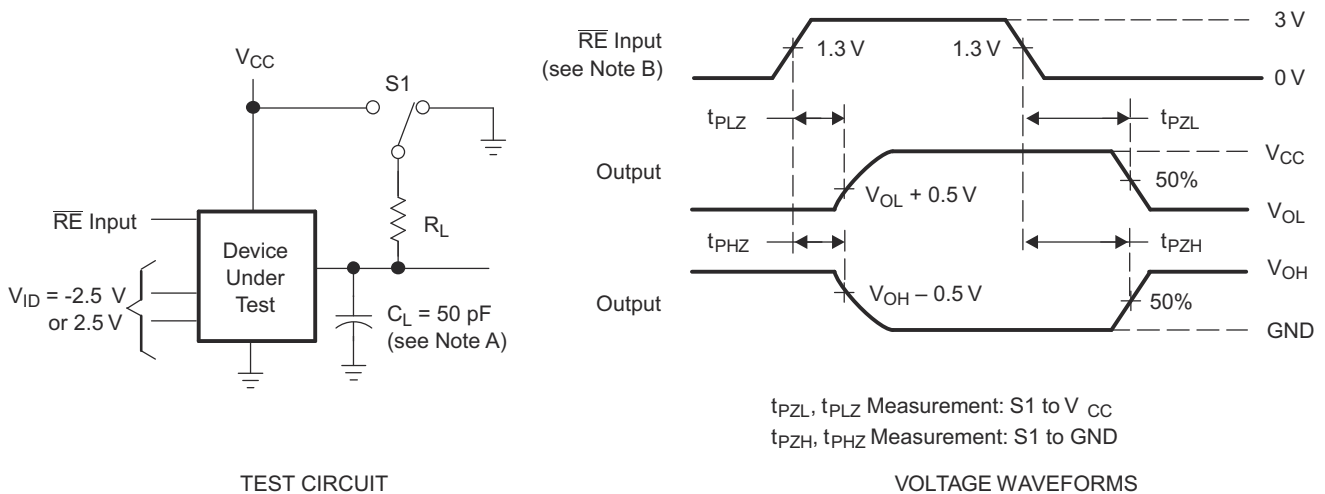
- A. C1, C2, and C3 include probe and jig capacitance.
- B. The input pulse is supplied by a generator having the following characteristics: PRR = 1 MHz, duty cycle = 50%, $t_r = t_f \leq 6\text{ns}$.

图 6-4. Driver Test Circuit and Voltage Waveforms



- A. C1, C2, and C3 include probe and jig capacitance.
- B. The input pulse is supplied by a generator having the following characteristics: PRR = 1 MHz, duty cycle = 50%, $t_r = t_f \leq 6\text{ns}$.

图 6-5. Receiver Test Circuit and Voltage Waveforms



- A. C1, C2, and C3 include probe and jig capacitance.
- B. The input pulse is supplied by a generator having the following characteristics: PRR = 1 MHz, duty cycle = 50%, $t_r = t_f \leq 6\text{ns}$.

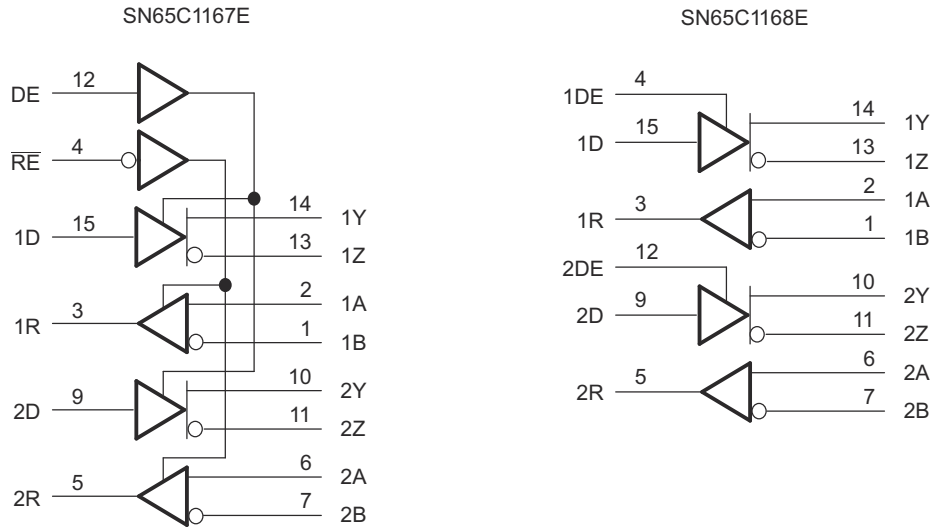
图 6-6. Receiver Test Circuit and Voltage Waveforms

7 Detailed Description

7.1 Overview

The SN65C1167E and SN65C1168E consist of dual drivers and dual receivers powered from a single 5V supply. These devices meet the requirements of TIA/EIA-422-B and ITU recommendation V.11.

7.2 Functional Block Diagram



Copyright © 2017, Texas Instruments Incorporated

7.3 Feature Description

7.3.1 Active High Driver Output Enables

Both drivers of SN65C1167E can be configured with the single DE logic input. Both drivers are set at high-impedance when disabled.

SN65C1168E drivers can be configured individually by 1DE and 2DE logic inputs. Both drivers are set at high-impedance when disabled.

7.3.2 Active Low Receiver Enables

Both SN65C1167E receivers can be configured with the single RE logic input. Receiver logic outputs are set at high-impedance when disabled.

8 Application and Implementation

备注

以下应用部分中的信息不属于 TI 器件规格的范围，TI 不担保其准确性和完整性。TI 的客户应负责确定器件是否适用于其应用。客户应验证并测试其设计，以确保系统功能。

8.1 Application Information

图 8-1 显示了一个典型的 RS-422 应用。一个发射器能够广播到多个接收节点，这些节点通过共享差分总线连接在一起。使用具有受控差分阻抗的绞合对电缆，并在最远的接收端放置一个终止电阻，以匹配传输线阻抗并最小化信号反射。

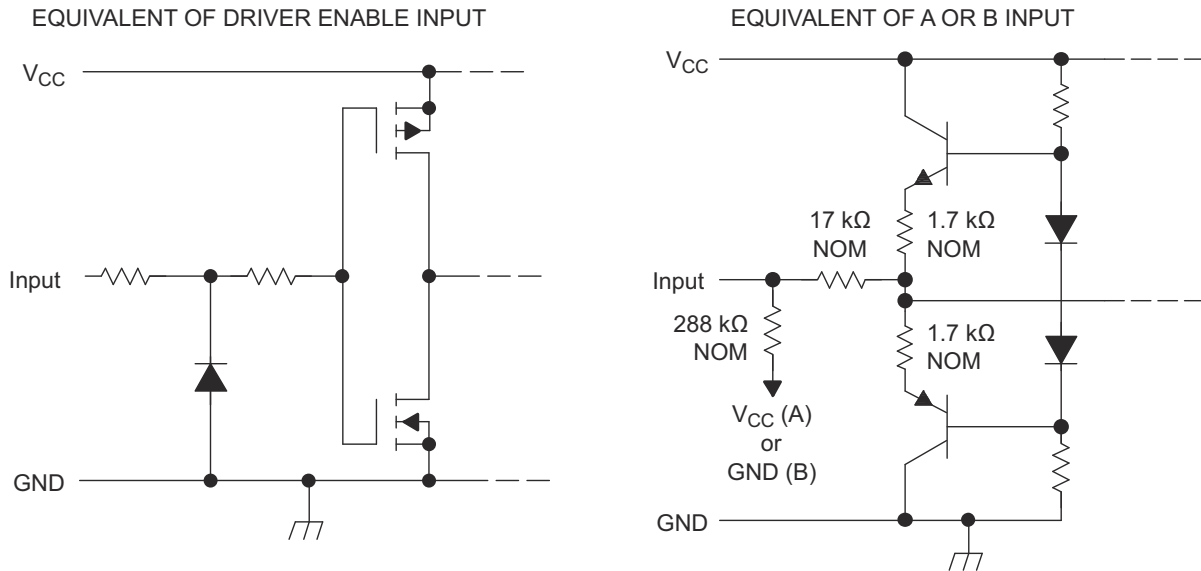


图 8-1. Schematic of Inputs

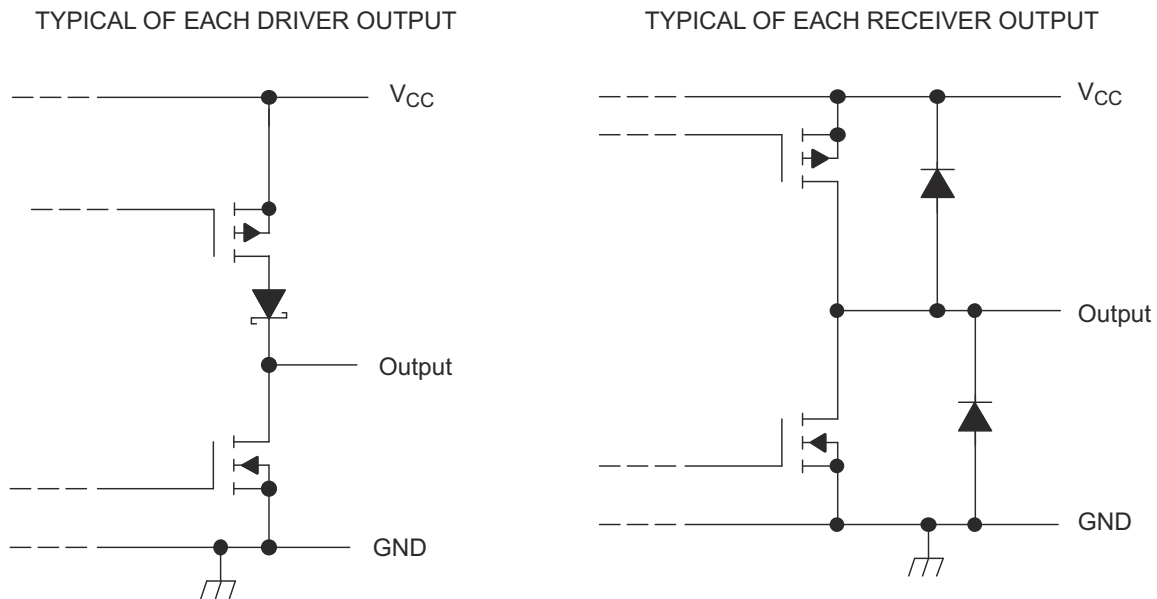


图 8-2. Schematic of Outputs

8.2 Typical Application

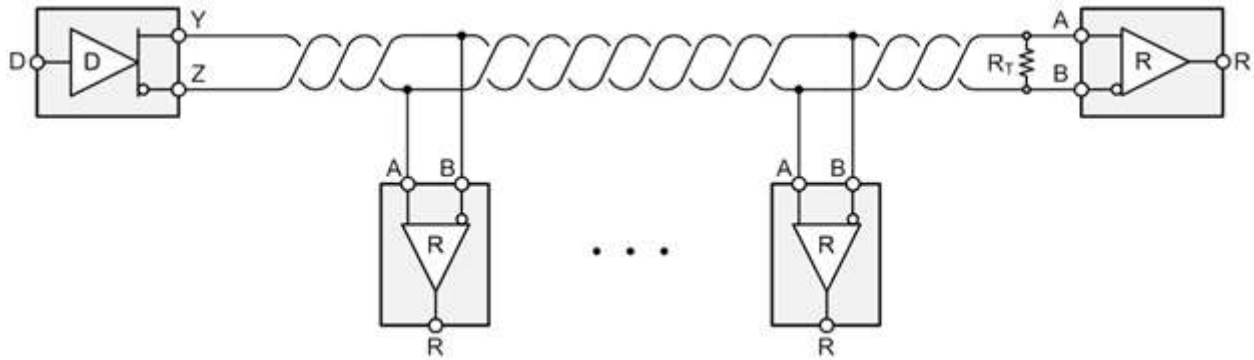


图 8-3. Typical RS-422 Application

8.2.1 Design Requirements

A typical RS-422 implementation using SN65C116xE requires the following:

- 5V power source.
- Connector that ensures the correct polarity for port pins.
- Cabling that supports the desired operating rate and transmission distance.

8.2.2 Detailed Design Procedure

Place the device close to bus connector to keep traces (stub) short to prevent adding reflections to the bus line. If desired, add external fail-safe biasing to ensure ± 200 mV on the A-B port when the driver circuit is disabled.

8.3 Power Supply Recommendations

Use a 5V power supply for V_{CC} place $0.1 \mu\text{F}$ bypass capacitors close to the power supply pins to reduce errors coupling in from noisy or high impedance power supplies.

9 Device and Documentation Support

9.1 Device Support

9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on Alert me to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.3 支持资源

[TI E2E™ 中文支持论坛](#)是工程师的重要参考资料，可直接从专家处获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题，获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的[使用条款](#)。

9.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

所有商标均为其各自所有者的财产。

9.5 静电放电警告



静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

9.6 术语表

[TI 术语表](#) 本术语表列出并解释了术语、首字母缩略词和定义。

10 Revision History

注：以前版本的页码可能与当前版本的页码不同

Changes from Revision B (May 2017) to Revision C (February 2024)	Page
• 将“器件信息”表更改为“封装信息”表.....	1
• Deleted the thermal packaging information from the <i>Absolute Maximum Ratings</i>	5
• Changed the <i>Thermal Information</i> table.....	6

Changes from Revision A (April 2007) to Revision B (May 2017)	Page
• 添加了 <i>ESD</i> 等级表、特性说明部分、器件功能模式、应用和实施部分、电源相关建议部分、器件和文档支持部分以及机械、封装和可订购信息部分.....	1
• Changed the Rise Time Max value From: 10 ns To: 8 ns in the <i>Driver Section Switching Characteristics</i> table.....	8
• Changed the Fall Time Max value From: 10 ns To: 8 ns in the <i>Driver Section Switching Characteristics</i> table.....	8
• Added Maximum switching frequency to the <i>Driver Section Switching Characteristics</i> table.....	8

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN65C1167ENSR	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	65C1167E	Samples
SN65C1167EPW	LIFEBUY	TSSOP	PW	16	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CB1167E	
SN65C1167EPWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CB1167E	Samples
SN65C1167ERGYR	ACTIVE	VQFN	RGY	16	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	CB1167	Samples
SN65C1168ENS	LIFEBUY	SO	NS	16	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	65C1168E	
SN65C1168ENSG4	LIFEBUY	SO	NS	16	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	65C1168E	
SN65C1168ENSR	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	65C1168E	Samples
SN65C1168EPW	LIFEBUY	TSSOP	PW	16	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CB1168E	
SN65C1168EPWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CB1168E	Samples
SN65C1168EPWRG4	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CB1168E	Samples
SN65C1168ERGYR	ACTIVE	VQFN	RGY	16	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	CB1168	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65C1167ENSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN65C1167EPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN65C1167ERGYR	VQFN	RGY	16	3000	330.0	12.4	3.8	4.3	1.5	8.0	12.0	Q1
SN65C1168ENSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN65C1168EPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN65C1168ERGYR	VQFN	RGY	16	3000	330.0	12.4	3.8	4.3	1.5	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65C1167ENSR	SO	NS	16	2000	356.0	356.0	35.0
SN65C1167EPWR	TSSOP	PW	16	2000	356.0	356.0	35.0
SN65C1167ERGYR	VQFN	RGY	16	3000	367.0	367.0	35.0
SN65C1168ENSR	SO	NS	16	2000	367.0	367.0	38.0
SN65C1168EPWR	TSSOP	PW	16	2000	356.0	356.0	35.0
SN65C1168ERGYR	VQFN	RGY	16	3000	356.0	356.0	35.0

TUBE


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
SN65C1167EPW	PW	TSSOP	16	90	530	10.2	3600	3.5
SN65C1168ENS	NS	SOP	16	50	530	10.5	4000	4.1
SN65C1168ENSG4	NS	SOP	16	50	530	10.5	4000	4.1
SN65C1168EPW	PW	TSSOP	16	90	530	10.2	3600	3.5

RGY (R-PVQFN-N16)

PLASTIC QUAD FLATPACK NO-LEAD



4203539-3/1 06/2011

- NOTES:
- All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - This drawing is subject to change without notice.
 - QFN (Quad Flatpack No-Lead) package configuration.
 - The package thermal pad must be soldered to the board for thermal and mechanical performance.
 - See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
 - Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
 - Package complies to JEDEC MO-241 variation BA.

RGY (R-PVQFN-N16)

PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

4206353-3/P 03/14

NOTE: All linear dimensions are in millimeters

RGY (R-PVQFN-N16)

PLASTIC QUAD FLATPACK NO-LEAD



4208122-3/P 03/14

- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <<http://www.ti.com>>.
 - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
 - F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



PACKAGE OUTLINE

NS0016A

SOP - 2.00 mm max height

SOP



NOTES:

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.

EXAMPLE STENCIL DESIGN

NS0016A

SOP - 2.00 mm max height

SOP



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:7X

4220735/A 12/2021

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.



NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



SOLDER MASK DETAILS

4220204/A 02/2017

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220204/A 02/2017

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

MECHANICAL DATA

NS (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14-PINS SHOWN



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

重要声明和免责声明

TI“按原样”提供技术和可靠性数据（包括数据表）、设计资源（包括参考设计）、应用或其他设计建议、网络工具、安全信息和其他资源，不保证没有瑕疵且不做任何明示或暗示的担保，包括但不限于对适销性、某特定用途方面的适用性或不侵犯任何第三方知识产权的暗示担保。

这些资源可供使用 TI 产品进行设计的熟练开发人员使用。您将自行承担以下全部责任：(1) 针对您的应用选择合适的 TI 产品，(2) 设计、验证并测试您的应用，(3) 确保您的应用满足相应标准以及任何其他功能安全、信息安全、监管或其他要求。

这些资源如有变更，恕不另行通知。TI 授权您仅可将这些资源用于研发本资源所述的 TI 产品的应用。严禁对这些资源进行其他复制或展示。您无权使用任何其他 TI 知识产权或任何第三方知识产权。您应全额赔偿因在这些资源的使用中对 TI 及其代表造成的任何索赔、损害、成本、损失和债务，TI 对此概不负责。

TI 提供的产品受 [TI 的销售条款](#) 或 [ti.com](#) 上其他适用条款/TI 产品随附的其他适用条款的约束。TI 提供这些资源并不会扩展或以其他方式更改 TI 针对 TI 产品发布的适用的担保或担保免责声明。

TI 反对并拒绝您可能提出的任何其他或不同的条款。

邮寄地址：Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2024，德州仪器 (TI) 公司